

DATA SHEET

74LVT32

3.3 V Quad 2-input OR gate

Product data
Supersedes data of 1996 Aug 28

2002 Sep 06

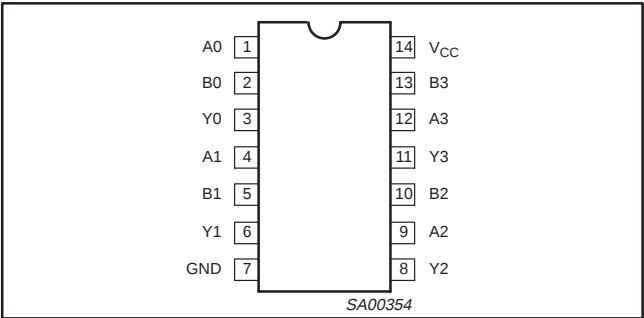
3.3 V Quad 2-input OR gate

74LVT32

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25\text{ }^{\circ}\text{C}$; $GND = 0\text{ V}$	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay An, Bn to Yn	$C_L = 50\text{ pF}$; $V_{CC} = 3.3\text{ V}$	2.6 3.2	ns
C_{IN}	Input capacitance	$V_I = 0\text{ V}$ or 3.0 V	3	pF
I_{CCL}	Total supply current	Outputs Low; $V_{CC} = 3.6\text{ V}$	1	mA

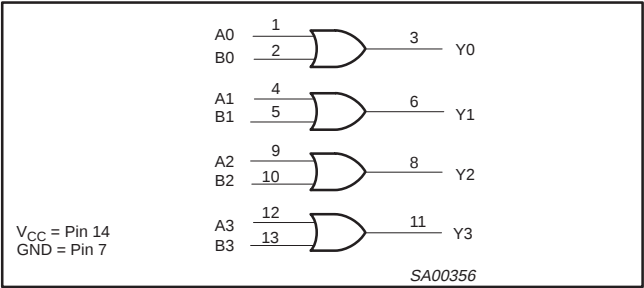
PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An, Bn	Data inputs
3, 6, 8, 11	Yn	Data outputs
7	GND	Ground (0 V)
14	V_{CC}	Positive supply voltage

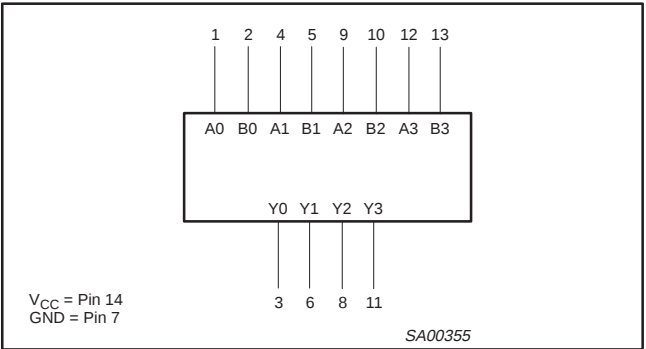
LOGIC DIAGRAM



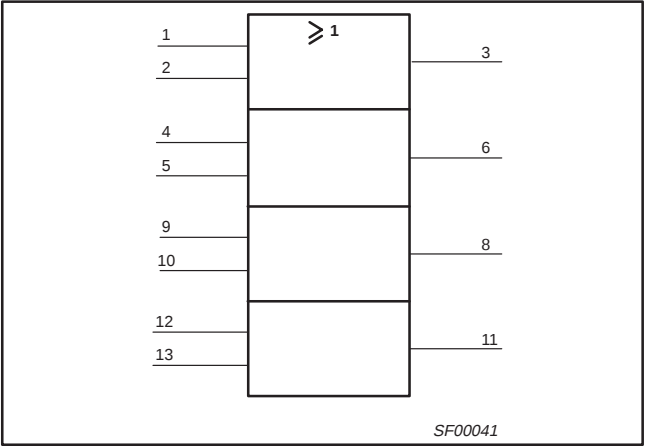
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40 °C to +85 °C	74LVT32D	74LVT32D	SOT108-1
14-Pin Plastic SSOP	-40 °C to +85 °C	74LVT32DB	74LVT32DB	SOT337-1
14-Pin Plastic TSSOP	-40 °C to +85 °C	74LVT32PW	74LVT32PWDH	SOT402-1

LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INPUTS		OUTPUT
Dna	Dnb	Qn
L	L	L
L	H	H
H	L	H
H	H	H

NOTES:

H = High voltage level
L = Low voltage level

3.3 V Quad 2-input OR gate

74LVT32

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		−0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	−50	mA
V_I	DC input voltage ³		−0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	−50	mA
V_{OUT}	DC output voltage ³	Output in Off or High state	−0.5 to +7.0	V
I_{OUT}	DC output current	Output in High state	−32	mA
		Output in Low state	64	
T_{stg}	Storage temperature range		−65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	2.7	3.6	V
V_I	Input voltage	0	5.5	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level Input voltage		0.8	V
I_{OH}	High-level output current		−20	mA
I_{OL}	Low-level output current		32	mA
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V
T_{amb}	Operating free-air temperature range	−40	+85	°C

3.3 V Quad 2-input OR gate

74LVT32

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 2.7 V; I _{IK} = −18 mA			−1.2	V
V _{OH}	High-level output voltage	V _{CC} = 2.7 to 3.6 V; I _{OH} = −100 μA	V _{CC} −0.2			V
		V _{CC} = 2.7 V; I _{OH} = −6 mA	2.4			
		V _{CC} = 3.0 V; I _{OH} = −20 mA	2.0			
V _{OL}	Low-level output voltage	V _{CC} = 2.7 V; I _{OL} = 100 μA			0.2	V
		V _{CC} = 2.7 V; I _{OL} = 24 mA			0.5	
		V _{CC} = 3.0 V; I _{OL} = 32 mA			0.5	
I _I	Input leakage current	V _{CC} = 0 or 3.6 V; V _I = 5.5 V			10	μA
		V _{CC} = 3.6 V; V _I = V _{CC} or GND			±1	
I _{OFF}	Output off current	V _{CC} = 0 V; V _I or V _O = 0 to 4.5 V			±100	μA
I _{CCH}	Quiescent supply current	V _{CC} = 3.6 V; Outputs High, V _I = GND or V _{CC} , I _O = 0			0.02	mA
I _{CCL}		V _{CC} = 3.6 V; Outputs Low, V _I = GND or V _{CC} , I _O = 0		1	2	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 3 V to 3.6 V; One input at V _{CC} −0.6 V, Other inputs at V _{CC} or GND			0.2	μA
C _I	Input capacitance	V _I = 3 V or 0		3		pF

NOTES:

1. All typical values are at $V_{CC} = 3.3 \text{ V}$ and $T_{amb} = 25^\circ\text{C}$.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

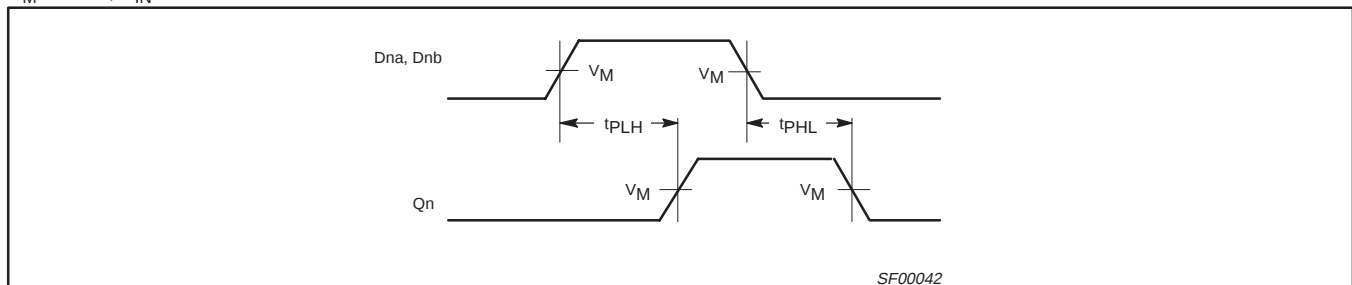
GND = 0 V; $t_R = t_F = 2.5 \text{ ns}$; $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$; $T_{amb} = -40^\circ\text{C}$ to $+85^\circ\text{C}$.

SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$			$V_{CC} = 2.7 \text{ V}$	
			MIN	TYP ¹	MAX	MAX	
t_{PLH} t_{PHL}	Propagation delay An, Bn to Yn	1	1.0 1.0	2.6 3.2	3.8 4.6	4.5 4.9	ns

NOTE:

1. All typical values are at $V_{CC} = 3.3 \text{ V}$ and $T_{amb} = 25^\circ\text{C}$.

AC WAVEFORMS

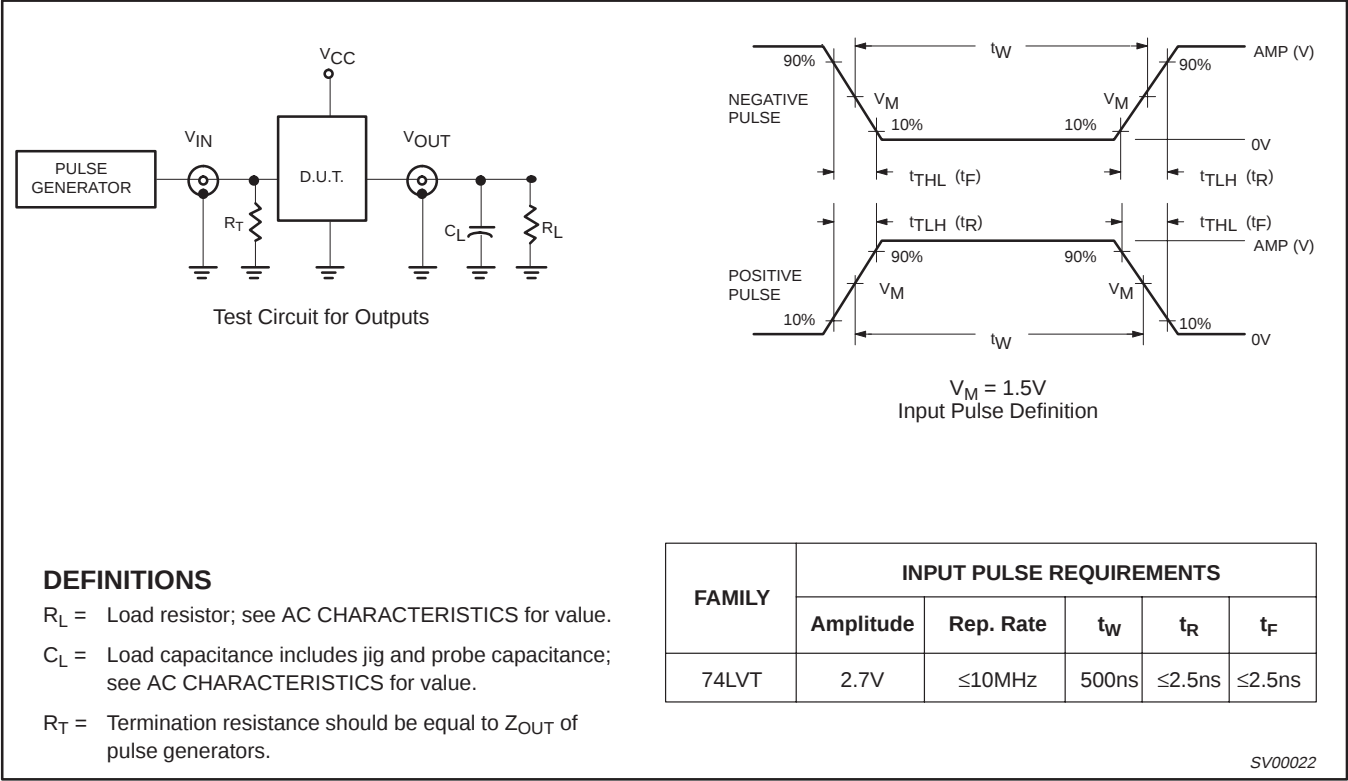
 $V_M = 1.5 \text{ V}$, $V_{IN} = \text{GND to } 2.7 \text{ V}$ 

Waveform 1. Propagation delay for inverting outputs

3.3 V Quad 2-input OR gate

74LVT32

TEST CIRCUIT AND WAVEFORMS

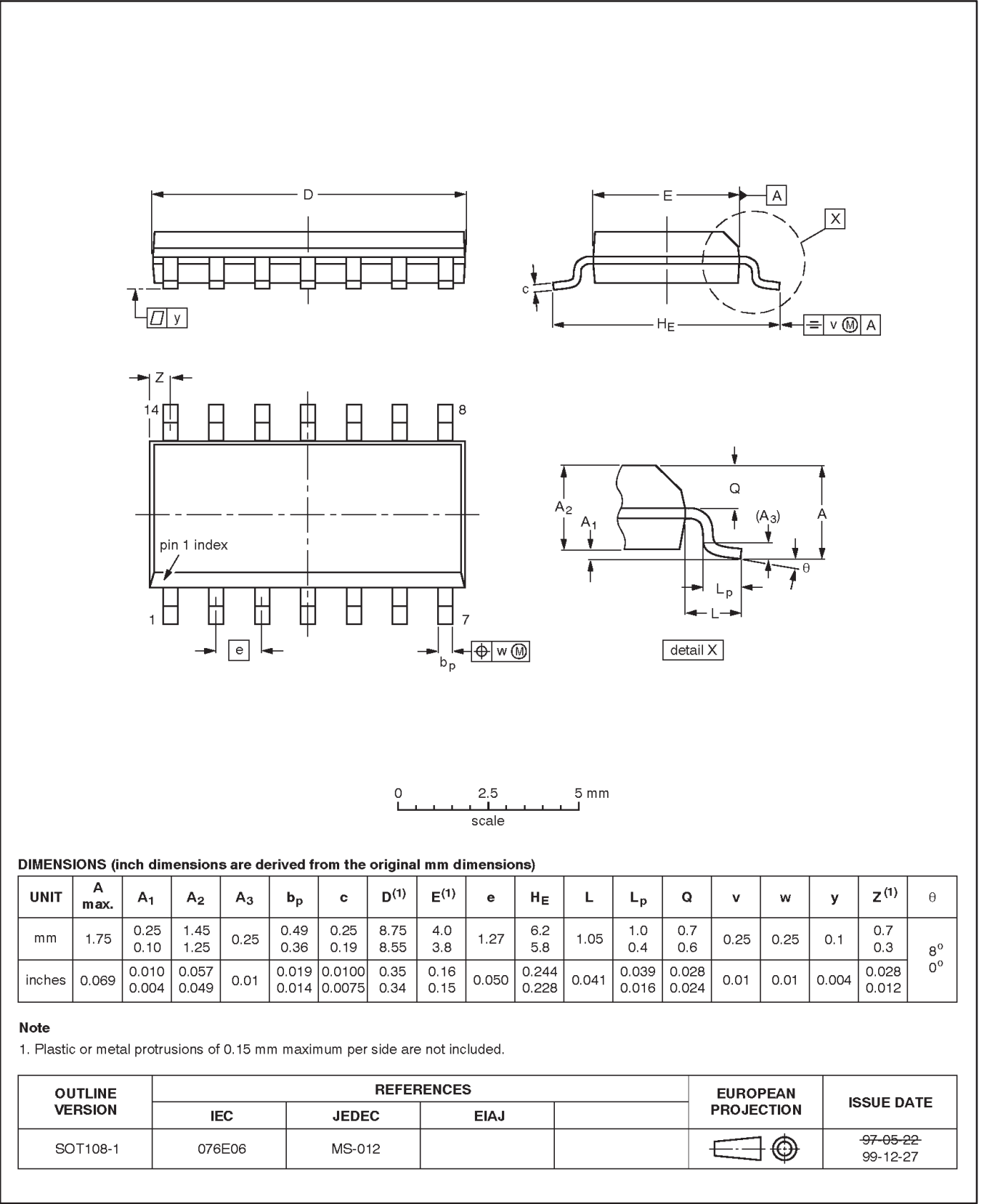


3.3 V Quad 2-input OR gate

74LVT32

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

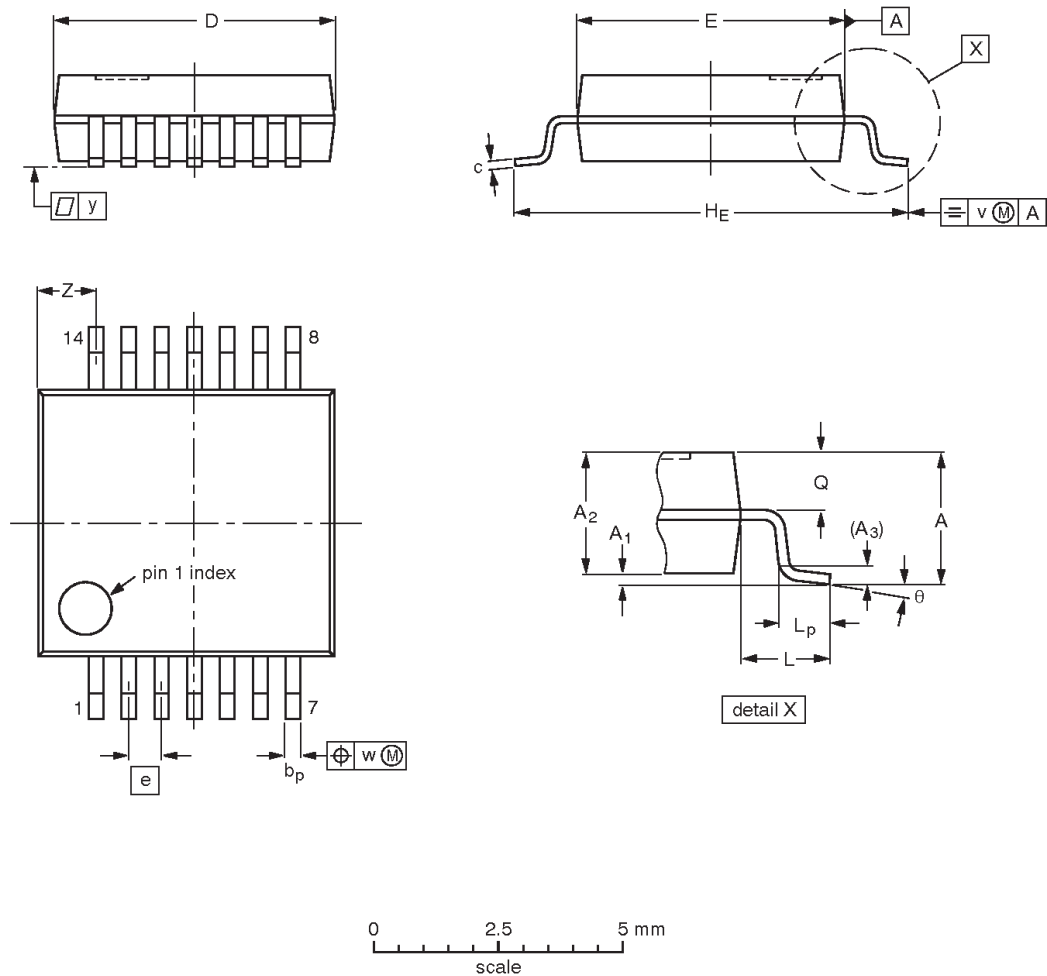


3.3 V Quad 2-input OR gate

74LVT32

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

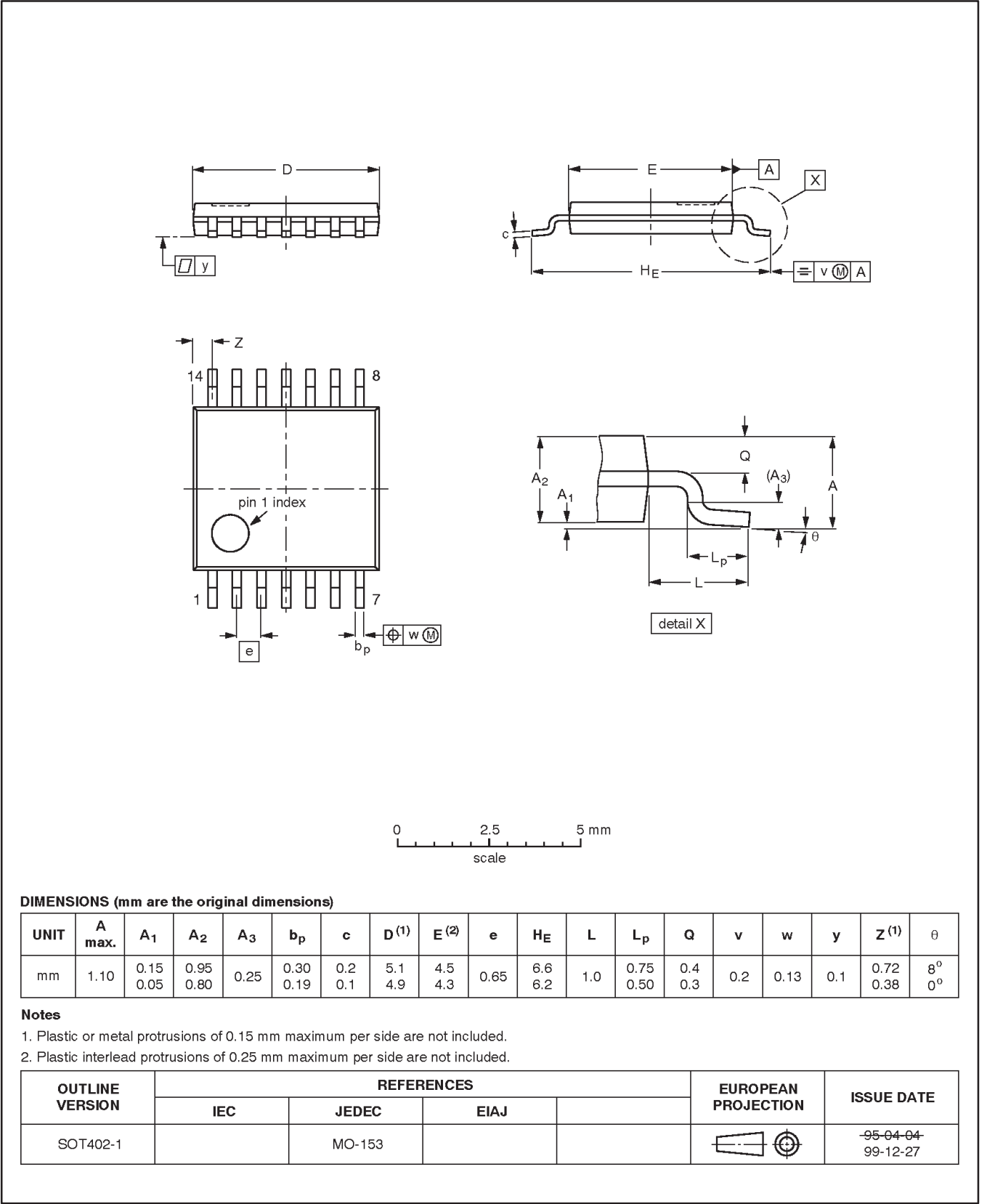
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT337-1		MO-150				96-01-18 99-12-27

3.3 V Quad 2-input OR gate

74LVT32

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



3.3 V Quad 2-input OR gate

74LVT32**REVISION HISTORY**

Rev	Date	Description
_2	2002 Sep 06	Product data (9397 750 10298); supersedes Product specification 74LVT32 of 1996 Aug 28. Modifications: There are no changes to any data. Document re-issued to improve quality of package outline drawings display only.
—	1996 Aug 28	Product specification; initial version. Engineering Change Notice: 853-1873 17244 (date: 1996 Aug 28).

3.3 V Quad 2-input OR gate

74LVT32

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Contact information

For additional information please visit
<http://www.semiconductors.philips.com>. Fax: +31 40 27 24825

© Koninklijke Philips Electronics N.V. 2002
 All rights reserved. Printed in U.S.A.

Date of release: 09-02

For sales offices addresses send e-mail to:
sales.addresses@www.semiconductors.philips.com.

Document order number:

9397 750 10298

Let's make things better.